NSN 5961-01-167-9130

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-9130 **Inclosure Material:** Glass and metal **Overall Length:** 1.380 inches **End Application:** 2350-01-089-1261 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.755 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 repetitive peak reverse voltage and 35.0 working peak reverse voltage **Current Rating Per Characteristic:** 120.00 amperes source cutoff current absolute and 800.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No